

### MAX22663-MAX22666

# Reinforced, Fast, Low-Power, Six-Channel Digital Isolators

### **Product Highlights**

- AEC-Q100 Qualification for /V Devices
- Reinforced Galvanic Isolation for Digital Signals
  - 16 Wide SOIC with 8mm Creepage and Clearance
  - Withstands 5kV<sub>RMS</sub> for 60s (V<sub>ISO</sub>)
  - Continuously Withstands 848V<sub>RMS</sub> (V<sub>IOWM</sub>)
  - Withstands ±12.8kV Surge between GNDA and GNDB with 1.2/50µs Waveform
  - High CMTI (50kV/µs, typ)
- Low Power Consumption
  - 0.71mW per Channel at 1Mbps with V<sub>DD</sub> = 1.8V
  - 1.34mW per Channel at 1Mbps with V<sub>DD</sub> = 3.3V
  - 3.21mW per Channel at 100Mbps with V<sub>DD</sub> = 1.8V
- Low Propagation Delay and Low Jitter
  - · Maximum Data Rate Up to 200Mbps
  - Low Propagation Delay 7ns (typ) at V<sub>DD</sub> = 3.3V
  - Clock Jitter RMS 11.1ps (typ)
- Safety Regulatory Approvals
  - UL According to UL1577
  - cUL According to CSA Bulletin 5A
  - VDE 0884-11 Reinforced Insulation (Pending)

### **Key Applications**

- Automotive
  - · Hybrid Electric Vehicle
  - Chargers
  - Battery Management System (BMS)
  - · Inverters

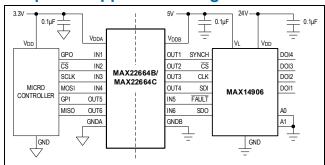
The MAX22663–MAX22666 are a family of 6-channel, reinforced, fast, low-power digital galvanic isolators using Analog Devices' proprietary process technology. All devices feature reinforced isolation with a withstand voltage rating of  $5kV_{RMS}$  for 60 seconds. Both automotive and general-purpose devices are rated for operation at ambient temperatures from -40°C to +125°C.

Devices with /V suffix are AEC-Q100 qualified. See the <u>Ordering Information</u> for all automotive grade part numbers.

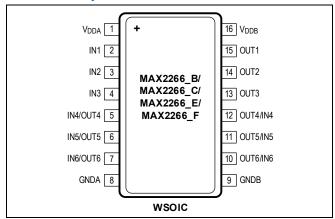
- Industrial
  - Isolated SPI, RS-232/422/485, CAN, Digital I/O
  - · Fieldbus Communications
  - Motor Control
  - · Medical Systems

These devices transfer digital signals between circuits with different power domains, using as little as 0.71mW per channel at 1Mbps (1.8V supply). The low-power feature reduces system dissipation, increases reliability, and enables compact designs.

### **Simplified Application Diagram**



### **Pin Description**



Devices are available with a maximum data rate of either 25Mbps or 200Mbps and with default-high or default-low outputs. The devices feature low propagation delay and low clock jitter, reducing system latency.

Independent 1.71V to 5.5V supplies on each side also make the devices suitable for use as level translators.

Three channels of the MAX22663 transmit digital signals in one direction, while the remaining three do in the opposite. The MAX22664 provides four channels for digital signal transmission, two of which travel in one direction and the other two in the opposite direction. The MAX22665 provides five channels for digital signal transmission in one direction and the other in the opposite direction. The MAX22666 features all six channels transmitting digital signals in one direction.

Ordering Information appears at end of the data sheet.

### **Absolute Maximum Ratings**

| V <sub>DDA</sub> to GNDA         | 0.3V to +6V               | OUT_ on Side B to GNDB ±30mA                          |
|----------------------------------|---------------------------|---|
| V <sub>DDB</sub> to GNDB         | 0.3V to +6V               | Continuous Power Dissipation (T <sub>A</sub> = +70°C) |
| IN_ on Side A to GNDA            | 0.3V to +6V               | Wide SOIC (derate 14.95mW/°C above +70°C) 1195.81mW   |
| IN_ on Side B to GNDB            | 0.3V to +6V               | Temperature Ratings                                   |
| OUT_ on Side A to GNDA0.3V to    | (V <sub>DDA</sub> + 0.3V) | Operating Temperature Range40°C to +125°C             |
| OUT_ on Side B to GNDB0.3V to    | (V <sub>DDB</sub> + 0.3V) | Maximum Junction Temperature+150°C                    |
| Short-Circuit Continuous Current |                           | Storage Temperature Range60°C to +150°C               |
| OUT_ on Side A to GNDA           | ±30mA                     | Lead Temperature (soldering, 10s)+300°C               |
| <u> </u>                         |                           | Soldering Temperature (reflow)+260°C                  |

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

### **Package Information**

| PACKAGE TYPE: 16 WIDE SOIC                             |                |
|--|----------------|
| Package Code   | W16MS+13       |
| Outline Number   | <u>21-0042</u> |
| Land Pattern Number                                    | 90-0107        |
| THERMAL RESISTANCE, FOUR LAYER BOARD:                  |                |
| Junction-to-Ambient ( $\theta_{JA}$ )                  | 66.90°C/W      |
| Junction-to-Case Thermal Resistance (θ <sub>JC</sub> ) | 42.50°C/W      |

Package thermal resistances were obtained using the method described in JEDEC specification JESD51-7, using a four-layer board. For detailed information on package thermal considerations, refer to <a href="http://www.maximintegrated.com/thermal-tutorial">http://www.maximintegrated.com/thermal-tutorial</a>.

For the latest package outline information and land patterns (footprints), go to <a href="http://www.maximintegrated.com/packages">http://www.maximintegrated.com/packages</a>. Note that a "+", "#", or "-" in the package code indicates RoHS status only. Package drawings may show a different suffix character, but the drawing pertains to the package regardless of RoHS status.

### **DC Electrical Characteristics**

 $(V_{DDA} - V_{GNDA} = 1.71 \text{V to } 5.5 \text{V}, V_{DDB} - V_{GNDB} = 1.71 \text{V to } 5.5 \text{V}, C_L = 15 \text{pF}, T_A = -40 ^{\circ}\text{C} \text{ to } +125 ^{\circ}\text{C}, \text{ unless otherwise noted. Typical values are at } V_{DDA} - V_{GNDA} = 3.3 \text{V}, V_{DDB} - V_{GNDB} = 3.3 \text{V}, V_{GNDA} = V_{GNDB}, T_A = +25 ^{\circ}\text{C}, \text{ unless otherwise noted.})$ 

| values are at V <sub>DDA</sub> - V <sub>GN</sub><br><b>PARAMETER</b> | SYMBOL                 | CONDITIONS                                 |                         | MIN                     | TYP  | MAX   | UNITS |   |
|--|------------------------|--|-------------------------|-------------------------|------|-------|-------|---|
| SUPPLY VOLTAGE   |                        |  |                         |                         |      |       |       |   |
| 0 1 1/1  | $V_{DDA}$              | Relative to GNDA                           |                         | 1.71                    |      | 5.5   | .,    |   |
| Supply Voltage   | $V_{DDB}$              | Relative to GNDB                           |                         | 1.71                    |      | 5.5   | V     |   |
| Undervoltage-Lockout<br>Threshold                                    | V <sub>UVLO</sub> _    | V <sub>DD</sub> _ rising                   |                         | 1.5                     | 1.6  | 1.66  | V     |   |
| Undervoltage-Lockout<br>Threshold Hysteresis                         | V <sub>UVLO_HYST</sub> |  |                         |                         | 45   |       | mV    |   |
| MAX22663 SUPPLY CU   | RRENT (Note 2)         |  |                         |                         |      |       |       |   |
|  |                        |  | V <sub>DDA</sub> = 5V   |                         | 1.23 | 2.28  |       |   |
|  |                        | 500kHz square                              | $V_{DDA} = 3.3V$        |                         | 1.22 | 2.25  |       |   |
|  |                        | wave, C <sub>L</sub> = 0pF                 | V <sub>DDA</sub> = 2.5V |                         | 1.21 | 2.24  |       |   |
| 0:1. 4.0   | l==.                   |  | V <sub>DDA</sub> = 1.8V |                         | 1.18 | 1.97  | ]     |   |
| Side A Supply Current  | I <sub>DDA</sub>       |  | V <sub>DDA</sub> = 5V   |                         | 7.83 | 10.26 | mA    |   |
|  |                        | 50MHz square                               | V <sub>DDA</sub> = 3.3V |                         | 6.47 | 8.71  |       |   |
|  |                        | wave, C <sub>L</sub> = 0pF                 | V <sub>DDA</sub> = 2.5V |                         | 5.90 | 8.03  |       |   |
|  |                        |  | V <sub>DDA</sub> = 1.8V |                         | 5.35 | 7.10  |       |   |
|  |                        |  | V <sub>DDB</sub> = 5V   |                         | 1.23 | 2.28  |       |   |
|  |                        | 500kHz square wave, C <sub>L</sub> = 0pF   | V <sub>DDB</sub> = 3.3V |                         | 1.22 | 2.25  | mA    |   |
|  |                        |  | V <sub>DDB</sub> = 2.5V |                         | 1.21 | 2.24  |       |   |
|  | I <sub>DDB</sub>       |  | V <sub>DDB</sub> = 1.8V |                         | 1.18 | 1.97  |       |   |
| Side B Supply Current  |                        |  | V <sub>DDB</sub> = 5V   |                         | 7.83 | 10.26 |       |   |
|  |                        |  | 50MHz square            | V <sub>DDB</sub> = 3.3V |      | 6.47  | 8.71  | _ |
|  |                        | wave, C <sub>L</sub> = 0pF                 | V <sub>DDB</sub> = 2.5V |                         | 5.90 | 8.03  |       |   |
|  |                        |  | V <sub>DDB</sub> = 1.8V |                         | 5.35 | 7.10  | 1     |   |
| MAX22664 SUPPLY CU   | RRENT (Note 2)         | I  |                         |                         |      |       | I     |   |
|  | <u> </u>               |  | V <sub>DDA</sub> = 5V   |                         | 1.09 | 2.01  |       |   |
|  |                        | 500kHz square                              | V <sub>DDA</sub> = 3.3V |                         | 1.07 | 1.99  |       |   |
|  |                        | wave, $C_L = 0pF$                          | V <sub>DDA</sub> = 2.5V |                         | 1.06 | 1.98  |       |   |
|  |                        |  | V <sub>DDA</sub> = 1.8V |                         | 1.04 | 1.66  |       |   |
| Side A Supply Current  | I <sub>DDA</sub>       |  | V <sub>DDA</sub> = 5V   |                         | 7.63 | 10.10 | mA    |   |
|  |                        | 50MHz square                               | V <sub>DDA</sub> = 3.3V |                         | 6.67 | 9.01  |       |   |
|  |                        | wave, C <sub>L</sub> = 0pF                 | $V_{DDA} = 2.5V$        |                         | 6.28 | 8.52  |       |   |
|  |                        |  | V <sub>DDA</sub> = 1.8V |                         | 5.84 | 7.67  | _     |   |
|  |                        |  | V <sub>DDB</sub> = 5V   |                         | 1.38 | 2.55  |       |   |
|  |                        | 500kHz square                              | V <sub>DDB</sub> = 3.3V |                         | 1.36 | 2.52  | -     |   |
|  |                        | wave, C <sub>L</sub> = 0pF                 | V <sub>DDB</sub> = 2.5V |                         | 1.35 | 2.51  | mA    |   |
| Side B Supply Current  | I <sub>DDB</sub>       |  | V <sub>DDB</sub> = 1.8V |                         | 1.32 | 2.28  |       |   |
|  |                        | 504  | FOMILIT COURSE          | V <sub>DDB</sub> = 5V   |      | 8.04  | 10.38 |   |
|  |                        | 50MHz square<br>wave, C <sub>L</sub> = 0pF | $V_{DDB} = 3.3V$        |                         | 6.27 | 8.41  | _     |   |

 $(V_{DDA} - V_{GNDA} = 1.71V \text{ to } 5.5V, V_{DDB} - V_{GNDB} = 1.71V \text{ to } 5.5V, C_L = 15pF, T_A = -40^{\circ}\text{C} \text{ to } +125^{\circ}\text{C}, \text{ unless otherwise noted. Typical values are at } V_{DDA} - V_{GNDA} = 3.3V, V_{DDB} - V_{GNDB} = 3.3V, V_{GNDA} = V_{GNDB}, T_A = +25^{\circ}\text{C}, \text{ unless otherwise noted.})$ 

| PARAMETER             | SYMBOL           | CON                            | IDITIONS                | MIN                        | TYP  | MAX                   | UNITS |      |      |  |
|-----------------------|------------------|--------------------------------|-------------------------|----------------------------|------|-----------------------|-------|------|------|--|
|                       |                  |                                | V <sub>DDB</sub> = 2.5V |                            | 5.54 | 7.53                  |       |      |      |  |
|                       |                  |                                | V <sub>DDB</sub> = 1.8V |                            | 4.87 | 6.53                  |       |      |      |  |
| MAX22665 SUPPLY CUF   | RRENT (Note 2)   |                                |                         | 1                          |      |                       |       |      |      |  |
|                       |                  |                                | V <sub>DDA</sub> = 5V   |                            | 0.94 | 1.74                  |       |      |      |  |
|                       |                  | 500kHz square                  | V <sub>DDA</sub> = 3.3V |                            | 0.93 | 1.72                  |       |      |      |  |
|                       |                  | wave, C <sub>L</sub> = 0pF     | V <sub>DDA</sub> = 2.5V |                            | 0.92 | 1.71                  |       |      |      |  |
|                       | ,                |                                | V <sub>DDA</sub> = 1.8V |                            | 0.90 | 1.34                  |       |      |      |  |
| Side A Supply Current | IDDA             | I <sub>DDA</sub>               |                         | V <sub>DDA</sub> = 5V      |      | 7.44                  | 9.96  | mA   |      |  |
|                       |                  | 50MHz square                   | V <sub>DDA</sub> = 3.3V |                            | 6.88 | 9.31                  |       |      |      |  |
|                       |                  | wave, C <sub>L</sub> = 0pF     | V <sub>DDA</sub> = 2.5V |                            | 6.64 | 9.03                  |       |      |      |  |
|                       |                  |                                | V <sub>DDA</sub> = 1.8V |                            | 6.32 | 8.23                  |       |      |      |  |
|                       |                  |                                | V <sub>DDB</sub> = 5V   |                            | 1.53 | 2.82                  |       |      |      |  |
|                       |                  | 500kHz square                  | V <sub>DDB</sub> = 3.3V |                            | 1.50 | 2.79                  |       |      |      |  |
|                       |                  | wave, C <sub>L</sub> = 0pF     | V <sub>DDB</sub> = 2.5V |                            | 1.50 | 2.78                  |       |      |      |  |
|                       | I <sub>DDB</sub> |                                | V <sub>DDB</sub> = 1.8V |                            | 1.45 | 2.59                  |       |      |      |  |
| Side B Supply Current |                  | IDDB                           |                         | V <sub>DDB</sub> = 5V      |      | 8.36                  | 10.64 | mA   |      |  |
|                       |                  | 50MHz square                   | V <sub>DDB</sub> = 3.3V |                            | 6.16 | 8.19                  |       |      |      |  |
|                       |                  | wave, C <sub>L</sub> = 0pF     | V <sub>DDB</sub> = 2.5V |                            | 5.24 | 7.10                  |       |      |      |  |
|                       |                  |                                | V <sub>DDB</sub> = 1.8V |                            | 4.45 | 6.01                  |       |      |      |  |
| MAX22666 SUPPLY CUF   | RRENT (Note 2)   |                                | - 1                     | u.                         |      |                       | ·     |      |      |  |
|                       |                  | ,                              | ,                       |                            |      | V <sub>DDA</sub> = 5V |       | 0.79 | 1.47 |  |
|                       |                  | 500kHz square                  | V <sub>DDA</sub> = 3.3V |                            | 0.78 | 1.45                  |       |      |      |  |
|                       |                  | wave, C <sub>L</sub> = 0pF     | V <sub>DDA</sub> = 2.5V |                            | 0.78 | 1.44                  | mA    |      |      |  |
|                       | ,                |                                | V <sub>DDA</sub> = 1.8V |                            | 0.75 | 1.02                  |       |      |      |  |
| Side A Supply Current | I <sub>DDA</sub> |                                | V <sub>DDA</sub> = 5V   |                            | 7.25 | 9.81                  |       |      |      |  |
|                       |                  | 50MHz square                   | V <sub>DDA</sub> = 3.3V |                            | 7.08 | 9.61                  |       |      |      |  |
|                       |                  | wave, C <sub>L</sub> = 0pF     | V <sub>DDA</sub> = 2.5V |                            | 7.00 | 9.52                  |       |      |      |  |
|                       |                  |                                | V <sub>DDA</sub> = 1.8V |                            | 6.78 | 8.79                  |       |      |      |  |
|                       |                  |                                | V <sub>DDB</sub> = 5V   |                            | 1.67 | 3.09                  |       |      |      |  |
|                       |                  | 500kHz square                  | V <sub>DDB</sub> = 3.3V |                            | 1.65 | 3.06                  |       |      |      |  |
|                       |                  | wave, C <sub>L</sub> = 0pF     | V <sub>DDB</sub> = 2.5V |                            | 1.64 | 3.05                  |       |      |      |  |
|                       |                  |                                | V <sub>DDB</sub> = 1.8V |                            | 1.59 | 2.89                  |       |      |      |  |
| Side B Supply Current | I <sub>DDB</sub> |                                | V <sub>DDB</sub> = 5V   |                            | 8.57 | 10.81                 | mA    |      |      |  |
|                       |                  | 50MHz square                   | V <sub>DDB</sub> = 3.3V |                            | 5.97 | 7.91                  |       |      |      |  |
|                       |                  | wave, C <sub>L</sub> = 0pF     | V <sub>DDB</sub> = 2.5V |                            | 4.89 | 6.62                  |       |      |      |  |
|                       |                  |                                | V <sub>DDB</sub> = 1.8V |                            | 3.97 | 5.44                  | 1     |      |      |  |
| LOGIC INTERFACE (IN_  | , OUT_)          | •                              |                         | •                          |      |                       | •     |      |      |  |
| Input High Voltage    | V <sub>IH</sub>  | 2.25V ≤ V <sub>DD</sub> _ ≤ 5. | 5V                      | 0.7 x<br>V <sub>DD</sub> _ |      |                       | V     |      |      |  |

 $(V_{DDA} - V_{GNDA} = 1.71 \text{V to } 5.5 \text{V}, V_{DDB} - V_{GNDB} = 1.71 \text{V to } 5.5 \text{V}, C_L = 15 \text{pF}, T_A = -40 ^{\circ}\text{C}$  to +125  $^{\circ}\text{C}$ , unless otherwise noted. Typical values are at  $V_{DDA} - V_{GNDA} = 3.3 \text{V}, V_{DDB} - V_{GNDB} = 3.3 \text{V}, V_{GNDA} = V_{GNDB}, T_A = +25 ^{\circ}\text{C}$ , unless otherwise noted.) (Note 1, Note 3)

| PARAMETER                         | SYMBOL          | CONDITIONS                        | MIN                         | TYP | MAX  | UNITS |
|-----------------------------------|-----------------|-----------------------------------|-----------------------------|-----|------|-------|
|                                   |                 | 1.71V ≤ V <sub>DD</sub> _ < 2.25V | 0.75 x<br>V <sub>DD</sub> _ |     |      |       |
| Input Low Voltage V <sub>IL</sub> | \/              | $2.25V \le V_{DD} \le 5.5V$       |                             |     | 8.0  |       |
|                                   | VIL.            | 1.71V ≤ V <sub>DD</sub> _ < 2.25V |                             |     | 0.7  | V     |
| Innut I bratavacia                | Vince           | MAX2266_B/E                       |                             | 410 |      | \/    |
| Input Hysteresis                  | $V_{HYS}$       | MAX2266_C/F                       |                             | 80  |      | mV    |
| Input Pullup Current              | I <sub>PU</sub> | MAX2266_B/C                       | -10                         | -5  | -1.5 | μA    |
| Input Pulldown Current            | I <sub>PD</sub> | MAX2266_E/F                       | 1.5                         | 5   | 10   | μA    |
| Input Capacitance                 | C <sub>IN</sub> | f <sub>SW</sub> = 1MHz            |                             | 2   |      | pF    |
| Output Voltage High               | V <sub>OH</sub> | I <sub>OUT</sub> = -4mA source    | V <sub>DD</sub> 0.4         |     |      | V     |
| Output Voltage Low                | V <sub>OL</sub> | I <sub>OUT</sub> = 4mA sink       |                             |     | 0.4  | V     |

### **Dynamic Characteristics - MAX2266\_C/MAX2266\_F**

 $(V_{DDA} - V_{GNDA} = 1.71 \text{V to } 5.5 \text{V}, V_{DDB} - V_{GNDB} = 1.71 \text{V to } 5.5 \text{V}, C_L = 15 \text{pF}, T_A = -40 ^{\circ}\text{C} \text{ to } +125 ^{\circ}\text{C}, \text{ unless otherwise noted. Typical values are at } V_{DDA} - V_{GNDA} = 3.3 \text{V}, V_{DDB} - V_{GNDB} = 3.3 \text{V}, V_{GNDA} = V_{GNDB}, T_A = +25 ^{\circ}\text{C}, \text{ unless otherwise noted.})$ 

| PARAMETER                      | SYMBOL            | CO                                      | NDITIONS                              | MIN                                  | TYP  | MAX  | UNITS |
|--------------------------------|-------------------|---|---------------------------------------|--------------------------------------|------|------|-------|
| Common-Mode Transient Immunity | CMTI              | IN_ = GND_ or V <sub>DD_</sub> (Note 5) |                                       |                                      | 50   |      | kV/μs |
| Marrian Data Data              | DP                | 2.25V ≤ V <sub>DD</sub> _ ≤ 5           | .5V                                   | 200                                  |      |      | N 41  |
| Maximum Data Rate              | DR <sub>MAX</sub> | 1.71V ≤ V <sub>DD</sub> _ < 2           |                                       | 150                                  |      |      | Mbps  |
| Minimum Dulgo Width            | D\\\              |   | 2.25V ≤ V <sub>DD</sub> _ ≤<br>5.5V   |                                      |      | 5    |       |
| Minimum Pulse Width            | PW <sub>MIN</sub> | IN_ to OUT_                             | 1.71V ≤ V <sub>DD</sub> _ < 2.25V     |                                      |      | 6.67 | ns    |
|                                |                   |   | 4.5V ≤ V <sub>DD</sub> _ ≤ 5.5V       | 4.4                                  | 6.2  | 9.5  |       |
|                                | <sup>‡</sup> PLH  |   | $3.0V \le V_{DD} \le 3.6V$            | 4.8                                  | 7.0  | 11.2 |       |
| Propagation Delay              |                   | IN_ to OUT_,<br>C <sub>L</sub> = 15pF   | 2.25V ≤ V <sub>DD</sub> _ ≤<br>2.75V  | 5.3                                  | 8.3  | 14.7 |       |
|                                |                   |   | 1.71V ≤ V <sub>DD</sub> _ ≤<br>1.89V  | 7.1                                  | 12.3 | 22.1 |       |
| ( <u>Figure 1</u> )            |                   | IN_ to OUT_,<br>C <sub>L</sub> = 15pF   | $4.5V \le V_{DD} \le 5.5V$            | 4.6                                  | 6.5  | 9.9  | ns    |
|                                |                   |   | $3.0V \le V_{DD} \le 3.6V$            | 5.0                                  | 7.3  | 11.6 |       |
|                                | t <sub>PHL</sub>  |   | IN_ to OUT_,<br>C <sub>L</sub> = 15pF | 2.25V ≤ V <sub>DD</sub> _ ≤<br>2.75V | 5.4  | 8.5  | 14.9  |
|                                |                   |   | 1.71V ≤ V <sub>DD</sub> _ ≤<br>1.89V  | 7.2                                  | 12.1 | 21.8 |       |
|                                |                   |   | $4.5V \le V_{DD} \le 5.5V$            |                                      | 0.4  | 2.0  |       |
|                                |                   |   | $3.0V \le V_{DD} \le 3.6V$            |                                      | 0.4  | 2.0  |       |
| Pulse Width Distortion         | PWD               | t <sub>PLH</sub> - t <sub>PHL</sub>     | 2.25V ≤ V <sub>DD</sub> _ ≤<br>2.75V  |                                      | 0.3  | 2.0  | ns    |
|                                |                   |   | 1.71V ≤ V <sub>DD</sub> _ ≤<br>1.89V  |                                      | 0    | 2.0  |       |
|                                | topuu             | $4.5V \le V_{DD} \le 5.5$               | 5V                                    |                                      |      | 3.7  |       |
|                                | SPLH              | $3.0V \le V_{DD} \le 3.6V$              |                                       |                                      |      | 4.7  | ns    |

 $(V_{DDA} - V_{GNDA} = 1.71V \text{ to } 5.5V, V_{DDB} - V_{GNDB} = 1.71V \text{ to } 5.5V, C_L = 15pF, T_A = -40^{\circ}\text{C} \text{ to } +125^{\circ}\text{C}, \text{ unless otherwise noted. Typical values are at } V_{DDA} - V_{GNDA} = 3.3V, V_{DDB} - V_{GNDB} = 3.3V, V_{GNDA} = V_{GNDB}, T_A = +25^{\circ}\text{C}, \text{ unless otherwise noted.}$ 

| PARAMETER  | SYMBOL                 | С                                  | ONDITIONS                            | MIN            | TYP                  | MAX                                  | UNITS                                   |  |     |    |
|--|------------------------|------------------------------------|--------------------------------------|----------------|----------------------|--------------------------------------|---|--|-----|----|
|  |                        | 2.25V ≤ V <sub>DD</sub> _ ≤        | £ 2.75V                              |                |                      | 6.9                                  |   |  |     |    |
|  |                        | 1.71V ≤ V <sub>DD</sub> _ ≤        | ≤ 1.89V                              |                |                      | 12.1                                 |   |  |     |    |
| Propagation Delay  |                        | 4.5V ≤ V <sub>DD</sub> _ ≤         | 5.5V                                 |                |                      | 4.0                                  |   |  |     |    |
| Skew Part-to-Part<br>(Same Channel)                                    | 1                      | 3.0V ≤ V <sub>DD</sub> _ ≤         | 3.6V                                 |                |                      | 4.9                                  |   |  |     |    |
| (Came Chamber)   | <sup>t</sup> SPHL      | 2.25V ≤ V <sub>DD</sub> _ ≤        | £ 2.75V                              |                |                      | 7.0                                  |   |  |     |    |
|  |                        | 1.71V ≤ V <sub>DD</sub> _ ≤        | ≤ 1.89V                              |                |                      | 11.8                                 |   |  |     |    |
| Propagation Delay Skew Channel-to- Channel (Same Direction) (Figure 1) | <sup>t</sup> SCSLH     | 1.71V ≤ V <sub>DD</sub> _ ≤ 5.5V   |                                      |                |                      | 2.0                                  | ns                                      |  |     |    |
| Propagation Delay Skew Channel-to- Channel (Same Direction (Figure 1)  | <sup>t</sup> SCSHL     | 1.71V ≤ V <sub>DD</sub> _≤         | ≤ 5.5V                               |                |                      | 2.0                                  | ns                                      |  |     |    |
|  | tscolн                 | 4.5V ≤ V <sub>DD</sub> _ ≤ 5.5V    |                                      |                |                      | 3.7                                  |   |  |     |    |
| Propagation Delay  |                        | $3.0V \le V_{DD_{\perp}} \le 3.6V$ |                                      |                |                      | 4.7                                  | 4.7<br>6.9<br>12.1<br>4.0<br>4.9<br>7.0 |  |     |    |
|  |                        | 2.25V ≤ V <sub>DD</sub> _ ≤ 2.75V  |                                      |                |                      | 6.9                                  |   |  |     |    |
| Skew Channel-to-   |                        | 1.71V ≤ V <sub>DD</sub> _ ≤ 1.89V  |                                      |                |                      | 12.1                                 |   |  |     |    |
| Channel (Opposite  |                        | $4.5V \le V_{DD} \le 5.5V$         |                                      |                |                      | 4.0                                  |   |  |     |    |
| Direction)   |                        | 3.0V ≤ V <sub>DD</sub> _ ≤ 3.6V    |                                      |                |                      | 4.9                                  |   |  |     |    |
|  | tscohl                 | 2.25V ≤ V <sub>DD</sub> _ ≤ 2.75V  |                                      |                |                      | 7.0                                  |   |  |     |    |
|  |                        |                                    |                                      |                |                      | 11.8                                 |   |  |     |    |
| Peak Eye Diagram Jitter  | t <sub>JIT(PK)</sub>   | 200Mbps                            |                                      |                | 100                  |                                      | ps                                      |  |     |    |
| Clock Jitter RMS   | t <sub>JCLK(RMS)</sub> | 500kHz clock ir                    | nput, rising/falling edges           |                | 11.1                 |                                      | ps                                      |  |     |    |
|  |                        |                                    | 4.5V ≤ V <sub>DD</sub> _ ≤ 5.5V      |                |                      | 8.0                                  |   |  |     |    |
|  |                        |                                    | $3.0V \le V_{DD} \le 3.6V$           |                |                      | 1.1                                  |   |  |     |    |
| Rise Time<br>( <u>Figure 1</u> )                                       | t <sub>R</sub>         | C <sub>L</sub> = 5pF               | 2.25V ≤ V <sub>DD</sub> _ ≤<br>2.75V |                |                      | 1.5                                  | ns                                      |  |     |    |
|  |                        |                                    | 1.71V ≤ V <sub>DD</sub> _ ≤<br>1.89V |                |                      | 2.4                                  |   |  |     |    |
|  |                        |                                    | $4.5V \le V_{DD} \le 5.5V$           |                |                      | 1.0                                  |   |  |     |    |
|  |                        |                                    | $3.0V \le V_{DD} \le 3.6V$           |                |                      | 1.4                                  |   |  |     |    |
| Fall Time<br>( <u>Figure 1</u> )                                       | t <sub>F</sub>         | t <sub>F</sub>                     | t <sub>F</sub> (                     | t <sub>F</sub> | C <sub>L</sub> = 5pF | 2.25V ≤ V <sub>DD</sub> _ ≤<br>2.75V |   |  | 1.9 | ns |
|  |                        |                                    | 1.71V ≤ V <sub>DD</sub> _ ≤<br>1.89V |                |                      | 3.0                                  |   |  |     |    |

## **Dynamic Characteristics - MAX2266\_B/MAX2266\_E**

 $(V_{DDA} - V_{GNDA} = 1.71 \text{V to } 5.5 \text{V}, V_{DDB} - V_{GNDB} = 1.71 \text{V to } 5.5 \text{V}, C_L = 15 \text{pF}, T_A = -40 ^{\circ}\text{C} \text{ to } +125 ^{\circ}\text{C}, \text{ unless otherwise noted. Typical values are at } V_{DDA} - V_{GNDA} = 3.3 \text{V}, V_{DDA} - V_{GNDA} = 3.3 \text{V}, V_{GNDA} = V_{GNDB}, T_A = +25 ^{\circ}\text{C}, \text{ unless otherwise noted.)} \\ (Note 2, Note 4))$ 

| PARAMETER                      | SYMBOL            | CONDITIONS                              | MIN | TYP | MAX | UNITS |
|--------------------------------|-------------------|---|-----|-----|-----|-------|
| Common-Mode Transient Immunity | СМТІ              | IN_ = GND_ or V <sub>DD_</sub> (Note 5) |     | 50  |     | kV/µs |
| Maximum Data Rate              | DR <sub>MAX</sub> |   | 25  |     |     | Mbps  |
| Minimum Pulse Width            | PW <sub>MIN</sub> | IN_ to OUT_                             |     |     | 40  | ns    |

 $(V_{DDA} - V_{GNDA} = 1.71 \text{V to } 5.5 \text{V}, V_{DDB} - V_{GNDB} = 1.71 \text{V to } 5.5 \text{V}, C_L = 15 \text{pF}, T_A = -40 ^{\circ}\text{C} \text{ to } +125 ^{\circ}\text{C}, \text{ unless otherwise noted. Typical values are at } V_{DDA} - V_{GNDA} = 3.3 \text{V}, V_{DDA} - V_{GNDA} = 3.3 \text{V}, V_{GNDA} = V_{GNDB}, T_A = +25 ^{\circ}\text{C}, \text{ unless otherwise noted.)}$ 

| PARAMETER   | SYMBOL               | co                                    | NDITIONS                             | MIN  | TYP  | MAX  | UNITS   |
|---|----------------------|---------------------------------------|--------------------------------------|------|------|------|---------|
| Glitch Rejection  |                      | IN_ to OUT_                           |                                      | 10   | 17   | 29   | ns      |
|   |                      |                                       | 4.5V ≤ V <sub>DD</sub> _ ≤ 5.5V      | 16.7 | 22.6 | 30.7 |         |
|   |                      |                                       | $3.0V \le V_{DD} \le 3.6V$           | 17.0 | 23.4 | 32.2 |         |
|   | $t_{PLH}$            | IN_ to OUT_,<br>C <sub>L</sub> = 15pF | 2.25V ≤ V <sub>DD</sub> _ ≤          | 17.7 | 24.8 | 35.3 |         |
|   |                      | CL = 15pr                             | 2.75V<br>1.71V ≤ V <sub>DD</sub> _ ≤ | 17.7 | 24.0 | 33.3 |         |
| Propagation Dolay   |                      |                                       | 1.71V ≤ V <sub>DD</sub> _ ≤<br>1.89V | 19.6 | 28.8 | 42.8 |         |
| Propagation Delay (Figure 1)  |                      |                                       | 4.5V ≤ V <sub>DD</sub> ≤ 5.5V        | 16.4 | 22.7 | 32.1 | ns      |
| ,   |                      |                                       | 3.0V ≤ V <sub>DD</sub> ≤ 3.6V        | 16.8 | 23.5 | 33.8 |         |
|   | t <sub>PHL</sub>     | IN_ to OUT_,                          | 2.25V ≤ V <sub>DD</sub> _ ≤          |      |      |      |         |
|   | THE                  | C <sub>L</sub> = 15pF                 | 2.75V                                | 17.3 | 24.8 | 36.7 |         |
|   |                      |                                       | 1.71V ≤ V <sub>DD</sub> _≤           | 19.0 | 28.4 | 43.7 |         |
|   |                      |                                       | 1.89V                                |      |      |      |         |
|   |                      |                                       | $4.5V \le V_{DD} \le 5.5V$           |      | 0.2  | 4.0  |         |
|   |                      |                                       | $3.0V \le V_{DD} \le 3.6V$           |      | 0.2  | 4.0  | _       |
| Pulse Width Distortion  | PWD                  | t <sub>PLH</sub> - t <sub>PHL</sub>   | 2.25V ≤ V <sub>DD</sub> _ ≤<br>2.75V |      | 0.3  | 4.0  | ns      |
|   |                      |                                       | 1.71V ≤ V <sub>DD</sub> ≤            |      | 0.0  | 4.0  |         |
|   |                      |                                       | 1.89V                                |      | 0.6  | 4.0  |         |
|   |                      | $4.5V \le V_{DD} \le 5.$              | 5V                                   |      |      | 14.0 |         |
|   | t <sub>SPLH</sub>    | $3.0V \le V_{DD} \le 3.$              | 6V                                   |      |      | 13.8 | -<br>ns |
|   | SPLH                 | 2.25V ≤ V <sub>DD</sub> _ ≤ 2         | 2.75V                                |      |      | 15.2 |         |
| Propagation Delay   |                      | 1.71V ≤ V <sub>DD</sub> _ ≤ 1         | 1.89V                                |      |      | 21.9 |         |
| Skew Part-to-Part (Same Channel)                                    |                      | 4.5V ≤ V <sub>DD</sub> _ ≤ 5.5V       |                                      |      |      | 13.0 | ns      |
| (==   | t <sub>SPHL</sub>    | 3.0V ≤ V <sub>DD</sub> _ ≤ 3.6V       |                                      |      |      | 13.5 |         |
|   |                      | 2.25V ≤ V <sub>DD</sub> _ ≤ 2.75V     |                                      |      |      | 15.4 |         |
|   |                      | 1.71V ≤ V <sub>DD</sub> ≤ 1           | 1.89V                                |      |      | 21.4 |         |
| Propagation Delay   | tscslh               | 1.71V ≤ V <sub>DD</sub> ≤ 5           | 5.5V                                 |      |      | 4.0  |         |
| Skew Channel-to-<br>Channel (Same<br>Direction) ( <i>Figure 1</i> ) | <sup>t</sup> SCSHL   | 1.71V ≤ V <sub>DD</sub> _ ≤ 5         | 5.5V                                 |      |      | 4.0  | ns      |
| , \   |                      | 4.5V ≤ V <sub>DD</sub> _ ≤ 5.         | 5V                                   |      |      | 14.0 |         |
|   |                      | $3.0V \le V_{DD} \le 3.$              | 6V                                   |      |      | 13.8 |         |
| D   | tscolh               | 2.25V ≤ V <sub>DD</sub> ≤ 2           | 2.75V                                |      |      | 15.2 |         |
| Propagation Delay<br>Skew Channel-to-                               |                      | 1.71V ≤ V <sub>DD</sub> ≤ 1           | 1.89V                                |      |      | 21.9 | -       |
| Channel (Opposite   |                      | 4.5V ≤ V <sub>DD</sub> ≤ 5.           |                                      |      |      | 13.0 | ns      |
| Direction)  |                      | 3.0V ≤ V <sub>DD</sub> ≤ 3.           | 6V                                   |      |      | 13.5 |         |
|   | <sup>t</sup> SCOHL   | 2.25V ≤ V <sub>DD</sub> ≤ 2           |                                      |      |      | 15.4 | 1       |
|   |                      | $1.71V \le V_{DD} \le 1.89V$          |                                      |      |      | 21.4 |         |
| Peak Eye Diagram Jitter   | t <sub>JIT(PK)</sub> | 25Mbps                                |                                      |      | 250  |      | ps      |
|   | 311(111)             |                                       | 4.5V ≤ V <sub>DD</sub> ≤ 5.5V        |      |      | 0.8  | F-5     |
| Rise Time   | 1                    | C - 5-5                               | $3.0V \le V_{DD} \le 3.6V$           |      |      | 1.1  | ns      |
| ( <u>Figure 1</u> )   | t <sub>R</sub>       | C <sub>L</sub> = 5pF                  | 2.25V ≤ V <sub>DD</sub> ≤            |      |      |      |         |
| ,   |                      |                                       | 2.75V                                |      |      | 1.5  |         |

 $(V_{DDA} - V_{GNDA} = 1.71V \text{ to } 5.5V, V_{DDB} - V_{GNDB} = 1.71V \text{ to } 5.5V, C_L = 15pF, T_A = -40^{\circ}\text{C} \text{ to } +125^{\circ}\text{C}, \text{ unless otherwise noted. Typical values are at } V_{DDA} - V_{GNDA} = 3.3V, V_{DDA} - V_{GNDA} = 3.3V, V_{GNDA} = V_{GNDB}, T_A = +25^{\circ}\text{C}, \text{ unless otherwise noted.})$ 

| PARAMETER                        | SYMBOL         | COND                 | MIN                                  | TYP | MAX | UNITS |    |
|----------------------------------|----------------|----------------------|--------------------------------------|-----|-----|-------|----|
|                                  |                |                      | 1.71V ≤ V <sub>DD</sub> _ ≤<br>1.89V |     |     | 2.4   |    |
| Fall Time<br>( <u>Figure 1</u> ) |                |                      | $4.5V \le V_{DD} \le 5.5V$           |     |     | 1.0   |    |
|                                  | t <sub>F</sub> | C <sub>L</sub> = 5pF | $3.0V \le V_{DD} \le 3.6V$           |     |     | 1.4   |    |
|                                  |                |                      | 2.25V ≤ V <sub>DD</sub> _ ≤<br>2.75V |     |     | 1.9   | ns |
|                                  |                |                      | 1.71V ≤ V <sub>DD</sub> _ ≤<br>1.89V |     |     | 3.0   |    |

- **Note 1:** General purpose devices are 100% production tested at  $T_A = +25$ °C. Specifications over temperature are guaranteed by design and characterization. Automotive devices are 100% production tested at  $T_A = +25$ °C and  $T_A = +125$ °C.
- Note 2: Not production tested. Guaranteed by design and characterization.
- **Note 3:** All currents into the device are positive. All currents out of the device are negative. All voltages are referenced to their respective grounds (GNDA or GNDB), unless otherwise noted.
- **Note 4:** All measurements are taken with  $V_{DDA} = V_{DDB}$ , unless otherwise noted.
- Note 5: CMTI is the maximum sustainable common-mode voltage slew rate while maintaining the correct output. CMTI applies to both rising and falling common-mode voltage edges. Tested with the transient generator connected between GNDA and GNDB (V<sub>CM</sub> = 1000V).

### **ESD Protection**

| PARAMETER | SYMBOL | CONDITIONS                          | VALUE | UNITS |
|-----------|--------|-------------------------------------|-------|-------|
| ESD       |        | Human Body Model, All Pins          | ±4    | kV    |
| ESD       |        | IEC 61000-4-2 Contact, GNDB to GNDA | ±8    | kV    |

### **Test Circuit and Timing Diagram**

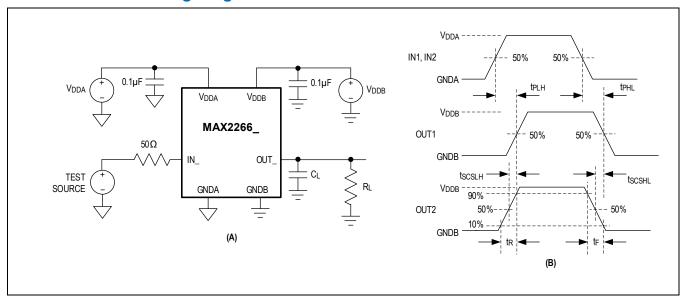


Figure 1. Test Circuit (A) and Timing Diagram (B)

### **Table 1. Insulation Characteristics**

| PARAMETER SYMBO | L CONDITIONS | VALUE | UNITS | 1 |
|-----------------|--------------|-------|-------|---|
|-----------------|--------------|-------|-------|---|

| Partial Discharge Test<br>Voltage           | V <sub>PR</sub>   | Method B1 = V <sub>IORM</sub> x 1.875 (t = 1s, partial discharge < 5pC)  | 2250              | V <sub>P</sub>   |
|---|-------------------|--|-------------------|------------------|
| Maximum Repetitive Peak Isolation Voltage   | V <sub>IORM</sub> | (Note 6)   | 1200              | V <sub>P</sub>   |
| Maximum Working Isolation Voltage           | $V_{\text{IOWM}}$ | Continuous RMS voltage (Note 6)  | 848               | V <sub>RMS</sub> |
| Maximum Transient Isolation Voltage         | $V_{IOTM}$        | t = 1s (Note 6)  | 7000              | V <sub>P</sub>   |
| Maximum Withstanding Isolation Voltage      | V <sub>ISO</sub>  | f <sub>SW</sub> = 60Hz, duration = 60s (Notes 6, 7)  | 5000              | V <sub>RMS</sub> |
| Maximum Surge Isolation Voltage             | V <sub>IOSM</sub> | Reinforced Insulation, test method per IEC 60065, V <sub>TEST</sub> = 1.6 x V <sub>IOSM</sub> = 12,800V <sub>PEAK</sub> (Notes 6, 9) | 8000              | V <sub>P</sub>   |
|   |                   | V <sub>IO</sub> = 500V, T <sub>A</sub> = 25°C  | >10 <sup>12</sup> |                  |
| Isolation Resistance                        | $R_{IO}$          | $V_{IO} = 500V, 100^{\circ}C \le T_{A} \le 125^{\circ}C$   | >10 <sup>11</sup> | Ω                |
|   |                   | V <sub>IO</sub> = 500V, T <sub>S</sub> = 150°C   | >10 <sup>9</sup>  |                  |
| Barrier Capacitance Side A to Side B        | C <sub>IO</sub>   | f <sub>SW</sub> = 1MHz (Note 8)  | 1.5               | pF               |
| Minimum Creepage Distance                   | CPG               |  | 8                 | mm               |
| Minimum Clearance Distance                  | CLR               |  | 8                 | mm               |
| Internal Clearance                          |                   | Distance through insulation  | 0.021             | mm               |
| Comparative Tracking Index                  | CTI               | Material Group II (IEC 60112)  | >400              |                  |
| Climate Category                            |                   |  | 40/125/21         |                  |
| Pollution Degree<br>(DIN VDE 0110, Table 1) |                   |  | 2                 |                  |

Note 6:  $V_{ISO}$ ,  $V_{IOWM}$ ,  $V_{IOTM}$ ,  $V_{IORM}$ , and  $V_{IOSM}$  are defined by the IEC 60747-5-5 standard.

Note 7: The product is qualified at  $V_{ISO}$  for 60s and 100% production tested at 120% of  $V_{ISO}$  for 1s.

Note 8: Capacitance is measured with all pins on the A side and the B side tied together.

 $\textbf{Note 9:} \ \, \textbf{Devices are immersed in oil during surge characterization}.$ 

### Safety Regulatory Approvals

### UL

The MAX22663-MAX22666 are certified under UL1577. For more details, refer to File E351759.

Rated up to 5000V<sub>RMS</sub> isolation voltage for single protection.

#### cUL (Equivalent to CSA notice 5A)

The MAX22663-MAX22666 are certified up to 5000V<sub>RMS</sub> for single protection. For more details, refer to File E351759.

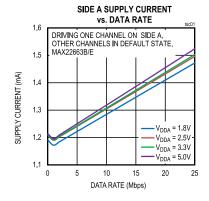
#### VDE (Pending)

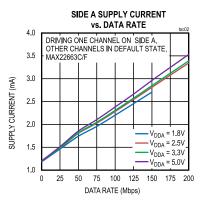
The MAX22663-MAX22666 are certified to DIN VDE V 0884-11: 2017-1. Reinforced Insulation, Maximum Transient Isolation Voltage 7000V<sub>PK</sub>, Maximum Repetitive Peak Isolation Voltage 1200V<sub>PK</sub>.

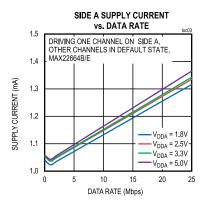
These couplers are suitable for "safe electrical insulation" only within the safety ratings. Compliance with the safety ratings shall be ensured by means of suitable protective circuits.

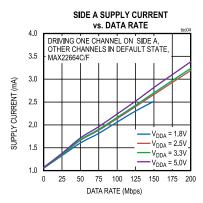
### **Typical Operating Characteristics**

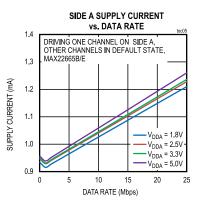
(V<sub>DDA</sub> - V<sub>GNDA</sub> = +3.3V, V<sub>DDB</sub> - V<sub>GNDB</sub> = +3.3V, V<sub>GNDA</sub> = V<sub>GNDB</sub>, T<sub>A</sub> = +25°C, unless otherwise noted.)

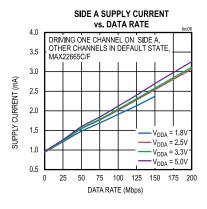


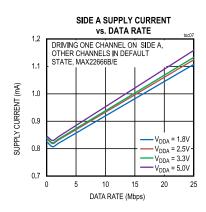


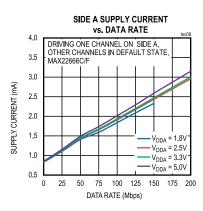


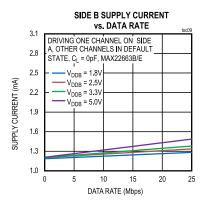




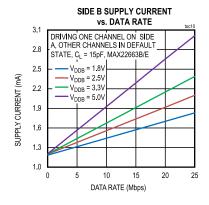


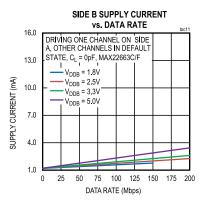


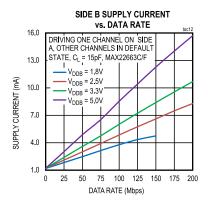


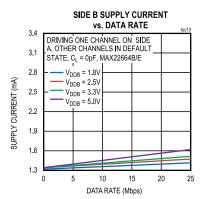


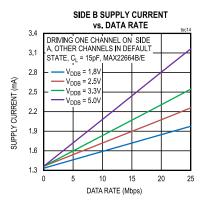
 $(V_{DDA} - V_{GNDA} = +3.3V, V_{DDB} - V_{GNDB} = +3.3V, V_{GNDA} = V_{GNDB}, T_A = +25^{\circ}C, unless otherwise noted.)$ 

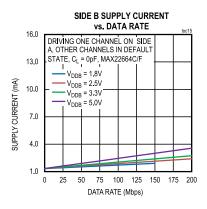


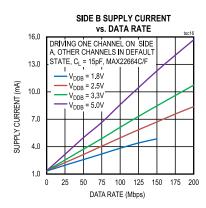


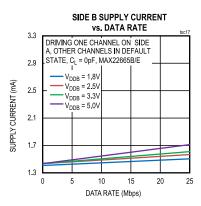


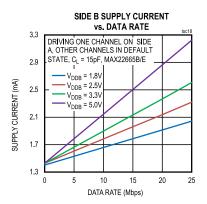




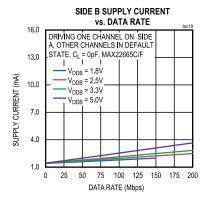


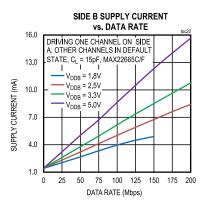


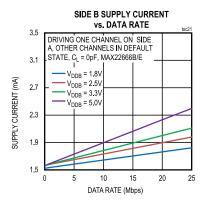


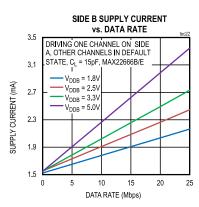


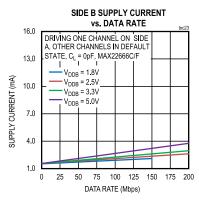
 $(V_{DDA} - V_{GNDA} = +3.3V, V_{DDB} - V_{GNDB} = +3.3V, V_{GNDA} = V_{GNDB}, T_A = +25^{\circ}C, unless otherwise noted.)$ 

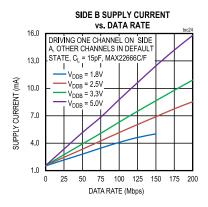


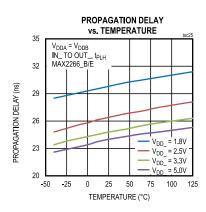


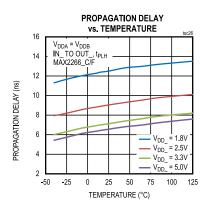


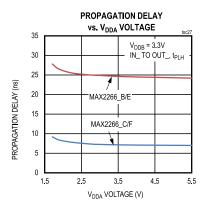




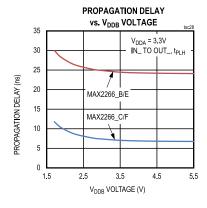


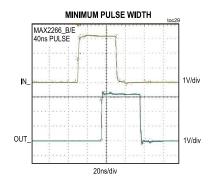


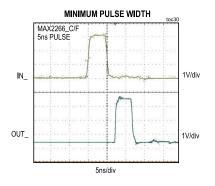


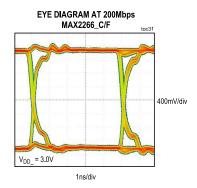


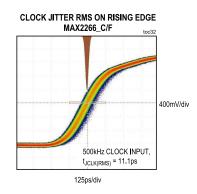
 $(V_{DDA} - V_{GNDA} = +3.3V, V_{DDB} - V_{GNDB} = +3.3V, V_{GNDA} = V_{GNDB}, T_A = +25$ °C, unless otherwise noted.)

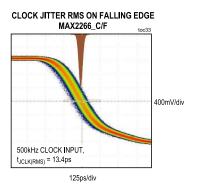


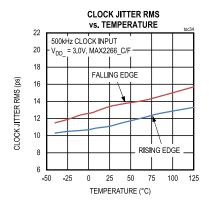




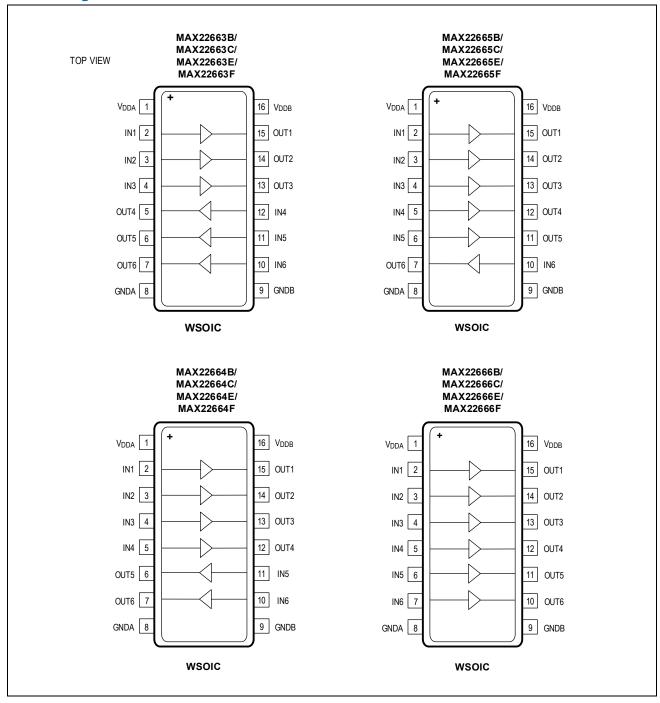








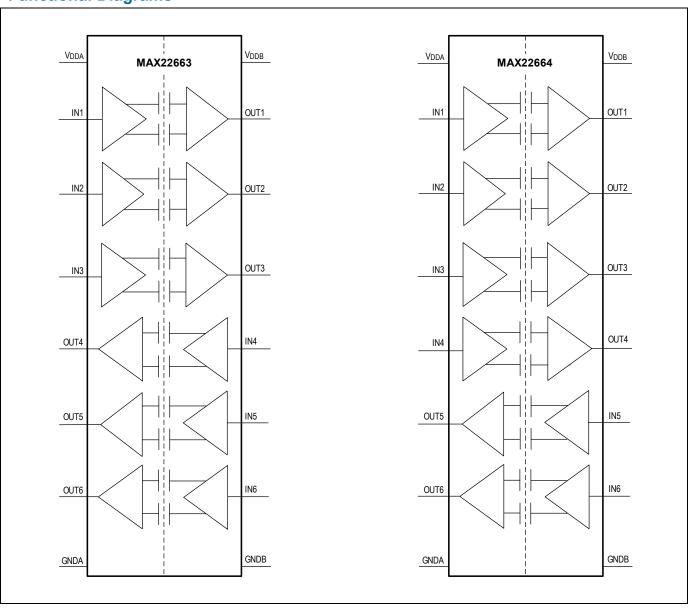
## **Pin Configurations**

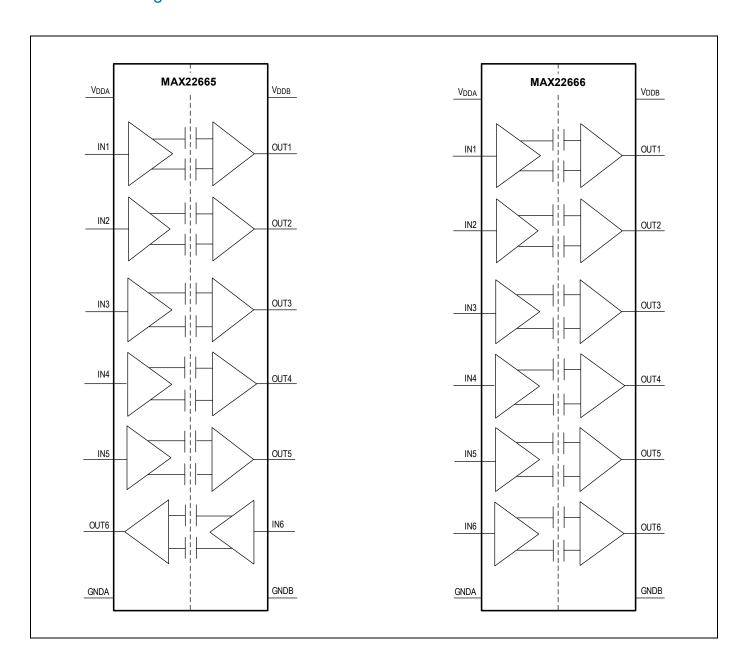


## **Pin Descriptions**

|          | PIN      |          |          | FUNCTION         |  |
|----------|----------|----------|----------|------------------|--|
| MAX22663 | MAX22664 | MAX22665 | MAX22666 | NAME             | FUNCTION   |
| 1        | 1        | 1        | 1        | V <sub>DDA</sub> | Power Supply Input for Side A. Bypass V <sub>DDA</sub> to GNDA with a  |
| '        | ı        | '        | I        | ▼ DDA            | 0.1μF ceramic capacitor as close as possible to the pin.   |
| 2        | 2        | 2        | 2        | IN1              | Logic Input 1 on Side A. Corresponds to Logic Output 1 on Side B.  |
| 3        | 3        | 3        | 3        | IN2              | Logic Input 2 on Side A. Corresponds to Logic Output 2 on Side B.  |
| 4        | 4        | 4        | 4        | IN3              | Logic Input 3 on Side A. Corresponds to Logic Output 3 on Side B.  |
| 12       | 5        | 5        | 5        | IN4              | Logic Input 4 on Side A/B. Corresponds to Logic Output 4 on Side B/A.  |
| 11       | 11       | 6        | 6        | IN5              | Logic Input 5 on Side A/B. Corresponds to Logic Output 5 on Side B/A.  |
| 10       | 10       | 10       | 7        | IN6              | Logic Input 6 on Side A/B. Corresponds to Logic Output 6 on Side B/A.  |
| 8        | 8        | 8        | 8        | GNDA             | Ground Reference for Side A.   |
| 9        | 9        | 9        | 9        | GNDB             | Ground Reference for Side B.   |
| 7        | 7        | 7        | 10       | OUT6             | Logic Output 6 on Side B/A. OUT6 is the logic output for the IN6 input on Side A/B.  |
| 6        | 6        | 11       | 11       | OUT5             | Logic Output 5 on Side B/A. OUT5 is the logic output for the IN5 input on Side A/B.  |
| 5        | 12       | 12       | 12       | OUT4             | Logic Output 4 on Side B/A. OUT4 is the logic output for the IN4 input on Side A/B.  |
| 13       | 13       | 13       | 13       | OUT3             | Logic Output 3 on Side B. OUT3 is the logic output for the IN3 input on Side A.  |
| 14       | 14       | 14       | 14       | OUT2             | Logic Output 2 on Side B. OUT2 is the logic output for the IN2 input on Side A.  |
| 15       | 15       | 15       | 15       | OUT1             | Logic Output 1 on Side B. OUT1 is the logic output for the IN1 input on Side A.  |
| 16       | 16       | 16       | 16       | $V_{\text{DDB}}$ | Power Supply Input for Side B. Bypass V <sub>DDB</sub> to GNDB with a 0.1µF ceramic capacitor as close as possible to the pin. |

## **Functional Diagrams**





### **Detailed Description**

The MAX22663-MAX22666 are a family of 6-channel reinforced digital isolators in a 16 Wide SOIC package, with an isolation rating of 5kV<sub>RMS</sub>. This family of devices offers all possible unidirectional channel configurations to accommodate any 6-channel design.

The MAX22663 features three channels transmitting digital signals in one direction and three channels transmitting in the opposite direction for applications such as isolated micro-controller interface. The MAX22664 offers four channels transmitting digital signals in one direction and two channels transmitting in the opposite direction, making them ideal candidates for applications such as isolated SPI. The MAX22665 provides five channels transmitting digital signals in one direction and one channel transmitting in the opposite direction. The MAX22666 features all six channels transmitting digital signals in one direction, which is suitable for applications such as isolated digital I/O.

The MAX22663-MAX22666 are available in a 16 Wide SOIC package with 8mm creepage and clearance, with an isolation rating of 5kV<sub>RMS</sub>. This family of digital isolators offers the low-power operation, high electromagnetic interference (EMI) immunity, and stable temperature performance through Analog Devices' proprietary process technology. The devices isolate different ground domains and block high-voltage/high-current transients from sensitive or human interface circuitry.

Devices are available with a maximum data rate of either 25Mbps (B/E version) or 200Mbps (C/F version). The MAX2266\_B/C feature default-high outputs. The MAX2266\_E/F feature default-low outputs. The default is the state the output assumes when the input is not powered or if the input is open-circuit. The MAX22663-MAX22666 has two supply inputs ( $V_{DDA}$  and  $V_{DDB}$ ) that independently set the logic levels on either side of the device.  $V_{DDA}$  and  $V_{DDB}$  are referenced to GNDA and GNDB, respectively. The MAX22663-MAX22666 also features a refresh circuit to ensure output accuracy when an input remains in the same state indefinitely.

#### **Digital Isolation**

The family of devices provides reinforced galvanic isolation for digital signals that are transmitted between two ground domains. The MAX22663-MAX22666 can withstand differences of up to 5kV<sub>RMS</sub> for up to 60 seconds, and up to 1200V<sub>PEAK</sub> of continuous isolation.

### **AEC-Q100 Qualification**

Devices with /V suffix are AEC-Q100 qualified. See the Ordering Information for all automotive grade part numbers.

#### **Level Shifting**

The wide supply voltage range of both  $V_{DDA}$  and  $V_{DDB}$  allows the MAX22663-MAX22666 to be used for level translation in addition to isolation.  $V_{DDA}$  and  $V_{DDB}$  can be independently set to any voltage from 1.71V to 5.5V. The supply voltage sets the logic level on the corresponding side of the isolator.

#### **Unidirectional Channels**

Each channel of the device is unidirectional; it only passes data in one direction, as shown in the <u>Functional Diagrams</u>. All devices feature six unidirectional channels that operate independently with guaranteed data rates from DC to 25Mbps (B/E version), or from DC to 200Mbps (C/F version). The output driver of each channel is push-pull, eliminating the need for pullup resistors. The outputs are able to drive both TTL and CMOS logic inputs.

#### Startup and Undervoltage-Lockout

The V<sub>DDA</sub> and V<sub>DDB</sub> supplies are both internally monitored for undervoltage conditions. Undervoltage events can occur during power-up, power-down, or during normal operation due to a sagging supply voltage. When an undervoltage condition is detected on either supply, all outputs go to their default states regardless of the state of the inputs as seen in *Table 2 Figure 2* through *Figure 5* show the behavior of the outputs during power-up and power-down.

**Table 2. Output Behavior During Undervoltage Conditions** 

| V <sub>IN</sub> _ | $V_{DDA}$    | $V_{DDB}$    | V <sub>OUTA</sub> | V <sub>OUTB</sub> |
|-------------------|--------------|--------------|-------------------|-------------------|
| 1                 | Powered      | Powered      | High              | High              |
| 0                 | Powered      | Powered      | Low               | Low               |
| Х                 | Undervoltage | Powered      | Default           | Default           |
| Х                 | Powered      | Undervoltage | Default           | Default           |

Note: "X" is don't care.

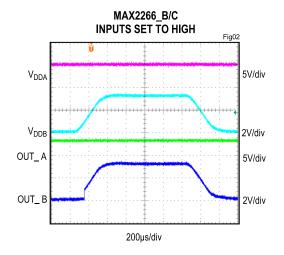


Figure 2. Undervoltage Lockout Behavior, MAX2266\_B/C, Inputs set to High

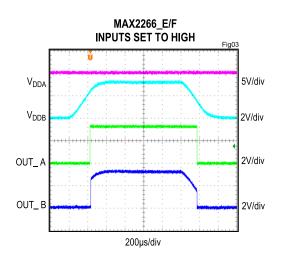


Figure 3. Undervoltage Lockout Behavior, MAX2266\_E/F, Inputs set to High

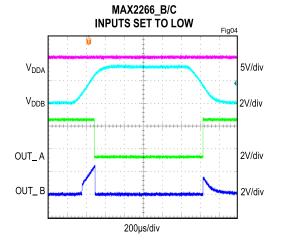


Figure 4. Undervoltage Lockout Behavior, MAX2266\_B/C, Inputs set to Low

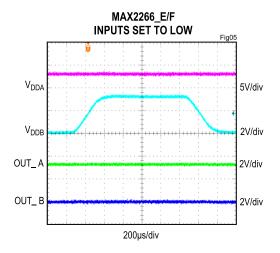


Figure 5. Undervoltage Lockout Behavior, MAX2266\_E/F, Inputs set to Low

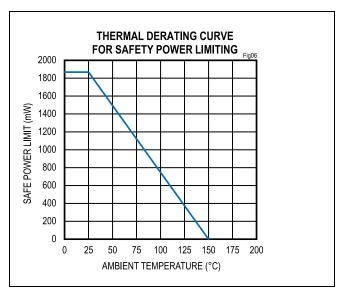
### **Safety Limit**

Damage to the IC can result in a low-resistance path to ground or to the supply and, without current limiting, the MAX22663-MAX22666 can dissipate excessive amounts of power. Excessive power dissipation can damage the die and result in damage to the isolation barrier, potentially causing downstream issues. <u>Table 3</u> shows the safety limits for the MAX22663–MAX22666.

The maximum safety temperature (T<sub>S</sub>) for the device is the 150°C maximum junction temperature specified in the <u>Absolute Maximum Ratings</u>. The power dissipation (P<sub>D</sub>) and junction-to-ambient thermal impedance ( $\theta_{JA}$ ) determine the junction temperature. Thermal impedance values ( $\theta_{JA}$  and  $\theta_{JC}$ ) are available in the <u>Package Information</u> section and power dissipation calculations are discussed in the <u>Calculating Power Dissipation</u> section. Calculate the junction temperature (T<sub>J</sub>) as:

$$T_J = T_A + (P_D \times \theta_{JA})$$

<u>Figure 6</u> shows the thermal derating curve for safety limiting the power of the devices, and <u>Figure 7</u> shows the thermal derating curve for safety limiting the current of the devices. Ensure that the junction temperature does not exceed 150°C.





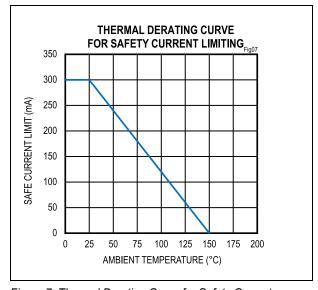


Figure 7. Thermal Derating Curve for Safety Current Limiting

### **Table 3. Safety Limiting Values**

| PARAMETER   | SYMBOL         | TEST CONDITIONS                               | MAX  | UNIT |
|---|----------------|---|------|------|
| Safety Current on Any Pin<br>(No Damage to Isolation Barrier) | IS             | T <sub>J</sub> = 150°C, T <sub>A</sub> = 25°C | 300  | mA   |
| Total Safety Power Dissipation                                | Ps             | T <sub>J</sub> = 150°C, T <sub>A</sub> = 25°C | 1868 | mW   |
| Maximum Safety Temperature                                    | T <sub>S</sub> |   | 150  | °C   |

### **Applications Information**

### **Power-Supply Sequencing**

The MAX22663-MAX22666 do not require any special power supply sequencing. The logic levels are set independently on either side by  $V_{DDA}$  and  $V_{DDB}$ . Each supply can be present over the entire specified range regardless of the level or presence of the other supply.

### **Power-Supply Decoupling**

To reduce ripple and the chance of introducing data errors, bypass  $V_{DDA}$  and  $V_{DDB}$  with  $0.1\mu F$  low-ESR ceramic capacitors to GNDA and GNDB, respectively. Place the bypass capacitors as close to the power supply input pins as possible.

### **Layout Considerations**

The PCB designer should follow some critical recommendations in order to get the best performance from the design.

- Keep the input/output traces as short as possible. To keep signal paths low-inductance, avoid using vias.
- Have a solid ground plane underneath the high-speed signal layer.
- Keep the area underneath the devices free from ground and signal planes. Any galvanic or metallic connection between Side A and Side B defeats the isolation.

### **Calculating Power Dissipation**

The required current for a given supply ( $V_{DDA}$  or  $V_{DDB}$ ) can be estimated by summing the current required for each channel. The supply current for a channel depends on whether the channel is an input or an output, the channel's data rate, and the capacitive or resistive load if it is an output. The typical current for input or output at any data rate can be estimated from the graphs in <u>Figure 8</u> and <u>Figure 9</u>. Note that the data in <u>Figure 8</u> and <u>Figure 9</u> are extrapolated from the supply current measurements in a typical operating condition.

The total current for a single channel is the sum of the no-load current (shown in <u>Figure 8</u> and <u>Figure 9</u>) which is a function of voltage and data rate, and the load current, which depends on the type of load. Current into a capacitive load is a function of the load capacitance, the switching frequency, and the supply voltage.

$$I_{CL} = C_L \times f_{SW} \times V_{DD}$$

where:

ICI is the current required to drive the capacitive load.

C<sub>I</sub> is the load capacitance on the isolator's output pin.

f<sub>SW</sub> is the switching frequency (bits per second/2).

V<sub>DD</sub> is the supply voltage on the output side of the isolator.

Current into a resistive load depends on the load resistance, the supply voltage, and the average duty cycle of the data waveform. The DC load current can be conservatively estimated by assuming the output is always high.

$$I_{RL} = V_{DD} \div R_{L}$$

where:

IRI is the current required to drive the resistive load.

V<sub>DD</sub> is the supply voltage on the output side of the isolator.

R<sub>L</sub> is the load resistance on the isolator's output pin.

**Example** (See <u>Figure 10</u>): A MAX22664C is operating with  $V_{DDA}$  = 2.5V,  $V_{DDB}$  = 3.3V, channel 1 operating at 20Mbps with a 15kΩ resistive load; channel 2 operating at 100Mbps with a 10pF capacitive load; channel 3 is not in use and the resistive load is negligible since the isolator is driving a CMOS input; channel 4 held high with a 10kΩ resistive load; channel 5 operating at 50Mbps with a 20kΩ resistive load; and channel 6 operating at 200Mbps with a 15pF capacitive load. Refer to <u>Table 4</u> and <u>Table 5</u> for  $V_{DDA}$  and  $V_{DDB}$  supply current calculation worksheets.

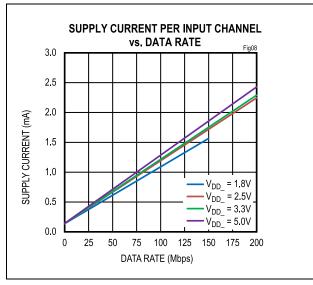
### $V_{DDA}$ must supply (with $V_{DDA} = 2.5V$ ):

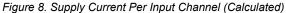
- Channel 1 is an input channel operating at 2.5V and 20Mbps, consuming 0.35mA, estimated from Figure 8.
- Channel 2 is an input channel operating at 2.5V and 100Mbps, consuming 1.19mA, estimated from <u>Figure 8</u>.
- Channels 3 and 4 are input channels operating at 2.5V with DC signal, consuming 0.14mA, estimated from <u>Figure 8</u>.
- Channel 5 is an output channel operating at 2.5V and 50Mbps, consuming 0.52mA, estimated from <u>Figure 9</u>.
- I<sub>RI</sub> on channel 5 for 20kΩ resistive load at 2.5V and switching at 50Mbps with 50% duty cycle is 0.0625mA.
- Channel 6 is an output channel operating at 2.5V and 200Mbps, consuming 1.31mA, estimated from <u>Figure 9</u>.
- I<sub>CL</sub> on channel 6 for 15pF capacitive load at 2.5V and 200Mbps is 3.75mA.

Total current for Side A = 7.46mA (typ).

### $V_{DDB}$ must supply (with $V_{DDB} = 3.3V$ ):

- Channel 1 is an output channel operating at 3.3V and 20Mbps, consuming 0.40mA, estimated from <u>Figure 9</u>.
- IRL on channel 1 for  $15k\Omega$  resistive load at 3.3V and switching at 20Mbps with 50% duty cycle is 0.11mA.
- Channel 2 is an output channel operating at 3.3V and 100Mbps, consuming 0.96mA, estimated from Figure 9.
- I<sub>CL</sub> on channel 2 for 10pF capacitive load at 3.3V and 100Mbps is 1.65mA.
- Channels 3 and 4 are output channels operating at 3.3V with DC signal, consuming 0.26mA, estimated from Figure 9.
- IRL on channel 4 for  $10k\Omega$  resistive load held at 3.3V is 0.33mA.
- Channel 5 is an input channel operating at 3.3V and 50Mbps, consuming 0.68mA, estimated from <u>Figure 8</u>.
- Channel 6 is an input channel operating at 3.3V and 200Mbps, consuming 2.29mA, estimated from <u>Figure 8</u>. Total current for Side B = 6.94mA (typ).





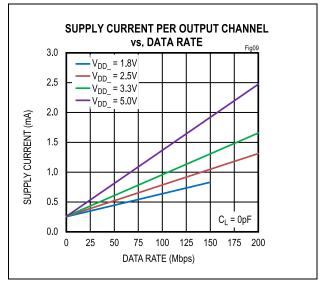


Figure 9. Supply Current Per Output Channel (Calculated)

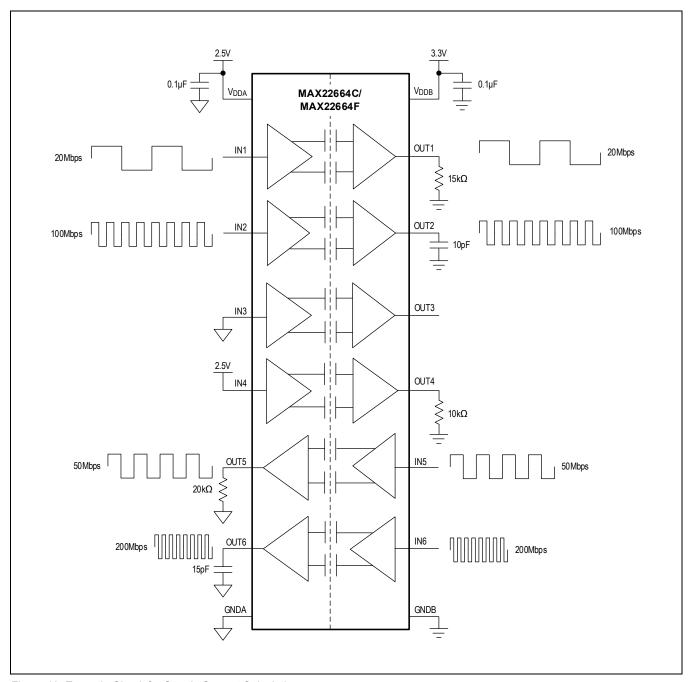


Figure 10. Example Circuit for Supply Current Calculation

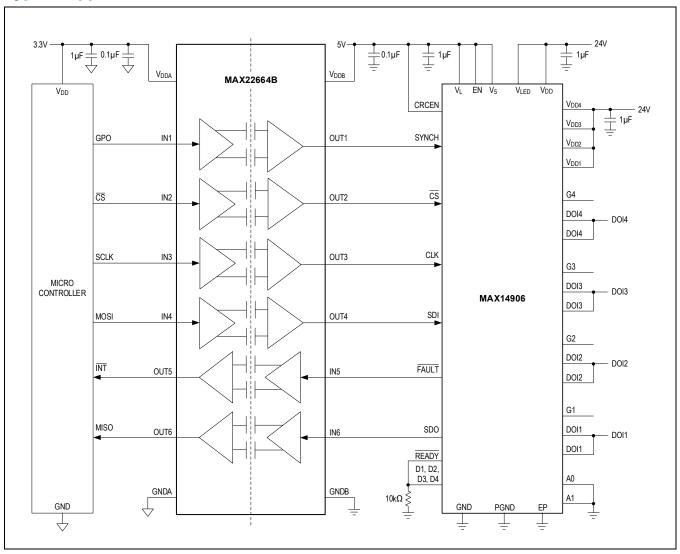
**Table 4. Side A Supply Current Calculation Worksheet** 

| SIDE A  | V <sub>DDA</sub> = 2.5V |                     |            |      |                           |                               |  |  |
|---------|-------------------------|---------------------|------------|------|---------------------------|-------------------------------|--|--|
| CHANNEL | IN/OUT                  | DATA RATE<br>(Mbps) | LOAD TYPE  | LOAD | "NO LOAD"<br>CURRENT (mA) | LOAD CURRENT (mA)             |  |  |
| 1       | IN                      | 20                  |            |      | 0.35                      |                               |  |  |
| 2       | IN                      | 100                 |            |      | 1.19                      |                               |  |  |
| 3       | IN                      | 0                   |            |      | 0.14                      |                               |  |  |
| 4       | IN                      | 0                   |            |      | 0.14                      |                               |  |  |
| 5       | OUT                     | 50                  | Resistive  | 20kΩ | 0.52                      | 2.5V / 20kΩ x 0.5 = 0.0625mA  |  |  |
| 6       | OUT                     | 200                 | Capacitive | 15pF | 1.31                      | 2.5V x 100MHz x 15pF = 3.75mA |  |  |
|         | Total: 7.46mA           |                     |            |      |                           |                               |  |  |

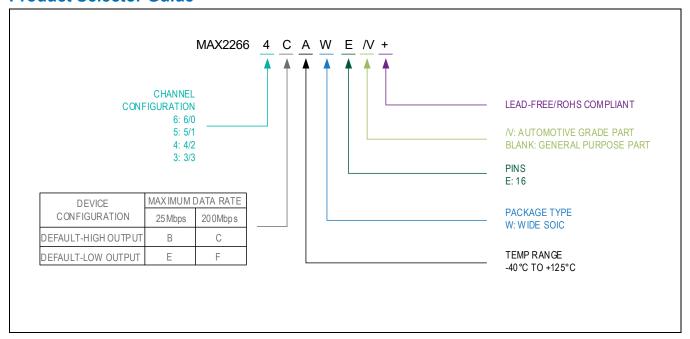
**Table 5. Side B Supply Current Calculation Worksheet** 

| SIDE B  | V <sub>DDB</sub> = 3.3V |                     |            |      |                           |  |  |  |
|---------|-------------------------|---------------------|------------|------|---------------------------|--|--|--|
| CHANNEL | IN/OUT                  | DATA RATE<br>(Mbps) | LOAD TYPE  | LOAD | "NO LOAD"<br>CURRENT (mA) | LOAD CURRENT (mA)                      |  |  |
| 1       | OUT                     | 20                  | Resistive  | 15kΩ | 0.40                      | $3.3V / 15k\Omega \times 0.5 = 0.11mA$ |  |  |
| 2       | OUT                     | 100                 | Capacitive | 10pF | 0.96                      | 3.3V x 50MHz x 10pF = 1.65mA           |  |  |
| 3       | OUT                     | 0                   |            |      | 0.26                      |  |  |  |
| 4       | OUT                     | 0                   | Resistive  | 10kΩ | 0.26                      | $3.3V / 10k\Omega = 0.33mA$            |  |  |
| 5       | IN                      | 50                  |            |      | 0.68                      |  |  |  |
| 6       | IN                      | 200                 |            |      | 2.29                      |  |  |  |
|         | Total: 6.94mA           |                     |            |      |                           |  |  |  |

## **Typical Application Circuit**



### **Product Selector Guide**



## **Ordering Information**

| PART NUMBER             | CHANNEL CONFIGURATION | DATA RATE<br>(Mbps) | DEFAULT<br>OUTPUT | ISOLATION<br>VOLTAGE (kV <sub>RMS</sub> ) | TEMPERATURE<br>RANGE | PIN-<br>PACKAGE |  |  |  |
|-------------------------|-----------------------|---------------------|-------------------|---|----------------------|-----------------|--|--|--|
| GENERAL PURPOSE DEVICES |                       |                     |                   |   |                      |                 |  |  |  |
| MAX22663BAWE+*          | 3/3                   | 25                  | High              | 5   | -40°C to +125°C      | 16-WSOIC        |  |  |  |
| MAX22663CAWE+*          | 3/3                   | 200                 | High              | 5   | -40°C to +125°C      | 16-WSOIC        |  |  |  |
| MAX22663EAWE+*          | 3/3                   | 25                  | Low               | 5   | -40°C to +125°C      | 16-WSOIC        |  |  |  |
| MAX22663FAWE+           | 3/3                   | 200                 | Low               | 5   | -40°C to +125°C      | 16-WSOIC        |  |  |  |
| MAX22664BAWE+           | 4/2                   | 25                  | High              | 5   | -40°C to +125°C      | 16-WSOIC        |  |  |  |
| MAX22664CAWE+           | 4/2                   | 200                 | High              | 5   | -40°C to +125°C      | 16-WSOIC        |  |  |  |
| MAX22664EAWE+*          | 4/2                   | 25                  | Low               | 5   | -40°C to +125°C      | 16-WSOIC        |  |  |  |
| MAX22664FAWE+*          | 4/2                   | 200                 | Low               | 5   | -40°C to +125°C      | 16-WSOIC        |  |  |  |
| MAX22665BAWE+*          | 5/1                   | 25                  | High              | 5   | -40°C to +125°C      | 16-WSOIC        |  |  |  |
| MAX22665CAWE+*          | 5/1                   | 200                 | High              | 5   | -40°C to +125°C      | 16-WSOIC        |  |  |  |
| MAX22665EAWE+*          | 5/1                   | 25                  | Low               | 5   | -40°C to +125°C      | 16-WSOIC        |  |  |  |
| MAX22665FAWE+           | 5/1                   | 200                 | Low               | 5   | -40°C to +125°C      | 16-WSOIC        |  |  |  |
| MAX22666BAWE+*          | 6/0                   | 25                  | High              | 5   | -40°C to +125°C      | 16-WSOIC        |  |  |  |
| MAX22666CAWE+           | 6/0                   | 200                 | High              | 5   | -40°C to +125°C      | 16-WSOIC        |  |  |  |
| MAX22666EAWE+*          | 6/0                   | 25                  | Low               | 5   | -40°C to +125°C      | 16-WSOIC        |  |  |  |
| MAX22666FAWE+*          | 6/0                   | 200                 | Low               | 5   | -40°C to +125°C      | 16-WSOIC        |  |  |  |

| AUTOMOTIVE DEVICES |     |     |      |   |                 |          |  |
|--------------------|-----|-----|------|---|-----------------|----------|--|
| MAX22663BAWE/V+*   | 3/3 | 25  | High | 5 | -40°C to +125°C | 16-WSOIC |  |
| MAX22663CAWE/V+*   | 3/3 | 200 | High | 5 | -40°C to +125°C | 16-WSOIC |  |
| MAX22663EAWE/V+*   | 3/3 | 25  | Low  | 5 | -40°C to +125°C | 16-WSOIC |  |
| MAX22663FAWE/V+*   | 3/3 | 200 | Low  | 5 | -40°C to +125°C | 16-WSOIC |  |
| MAX22664BAWE/V+*   | 4/2 | 25  | High | 5 | -40°C to +125°C | 16-WSOIC |  |
| MAX22664CAWE/V+    | 4/2 | 200 | High | 5 | -40°C to +125°C | 16-WSOIC |  |
| MAX22664EAWE/V+*   | 4/2 | 25  | Low  | 5 | -40°C to +125°C | 16-WSOIC |  |
| MAX22664FAWE/V+*   | 4/2 | 200 | Low  | 5 | -40°C to +125°C | 16-WSOIC |  |
| MAX22665BAWE/V+*   | 5/1 | 25  | High | 5 | -40°C to +125°C | 16-WSOIC |  |
| MAX22665CAWE+/V*   | 5/1 | 200 | High | 5 | -40°C to +125°C | 16-WSOIC |  |
| MAX22665EAWE+/V*   | 5/1 | 25  | Low  | 5 | -40°C to +125°C | 16-WSOIC |  |
| MAX22665FAWE+/V*   | 5/1 | 200 | Low  | 5 | -40°C to +125°C | 16-WSOIC |  |
| MAX22666BAWE+/V*   | 6/0 | 25  | High | 5 | -40°C to +125°C | 16-WSOIC |  |
| MAX22666CAWE+/V*   | 6/0 | 200 | High | 5 | -40°C to +125°C | 16-WSOIC |  |
| MAX22666EAWE+/V*   | 6/0 | 25  | Low  | 5 | -40°C to +125°C | 16-WSOIC |  |
| MAX22666FAWE+/V*   | 6/0 | 200 | Low  | 5 | -40°C to +125°C | 16-WSOIC |  |

<sup>\*</sup>Future product - contact Analog Devices for availability.

## **Chip Information**

PROCESS: BICMOS

<sup>+</sup>Denotes a lead (Pb)–free/RoHS-compliant package.

<sup>/</sup>V Denotes an automotive qualified part.

### **Revision History**

| REVISION<br>NUMBER | REVISION DATE | DESCRIPTION  | PAGES<br>CHANGED |
|--------------------|---------------|--|------------------|
| 0                  | 12/22         | Release for Market Intro   | _                |
| 1                  | 9/23          | Removed future product designation from MAX22666CAWE+ in the Ordering Information section        | 26               |
| 2                  | 12/23         | Removed future product designation from MAX22663FAWE+ in the <i>Ordering Information</i> section | 26               |
| 3                  | 6/24          | Removed future product designation from MAX22664BAWE+ in the <i>Ordering Information</i> section | 26               |